

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

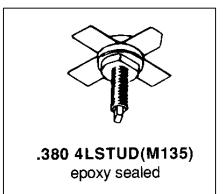
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## **SD1015**

# RF AND MICROWAVE TRANSISTORS 108–152MHz APPLICATIONS

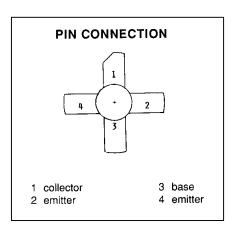
### **Features**

- FM CLASS C TRANSISTOR
- FREQUENCY 150 MHz
- POWER OUT 30W
- POWER GAIN 10dB
- GOLD METALLIZATION
- COMMON EMITTER



#### **DESCRIPTION:**

The SD1015 is a 28V gold metallized epitaxial silicon NPN planar transistor designed for 108–152MHz FM applications. This device utilizes diffused emitter resistors to achieve infinite VSWR at rated operating conditions.



### ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	36.0	V
V <sub>CEO</sub>	Collector-Emitter Voltage	18.0	V
V <sub>CES</sub>	Collector-Emitter Voltage	36.0	V
$V_{EBO}$	Emitter-Base Voltage	4.0	V
Ic	Collector Current	1.0	Α
$P_{TOT}$	Total Power Dissipation	10.0	W
T <sub>STG</sub>	Storage Temperature	- 65 to + 150	°C
Τ <sub>J</sub>	Junction Temperature	+200	°C

#### Thermal Data

R <sub>TH(j-c)</sub>	Junction-Case Thermal Resistance	4.4	°C/W			



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# ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

### **STATIC**

Symbol	Test Conditions	Value			Units	
		Min.	Тур.	Max.	Ullits	
BV <sub>CES</sub>	I <sub>C</sub> = 200 mA	$V_{BE} = 0 V$	65.0			V
BV <sub>CEO</sub>	I <sub>C</sub> = 200 mA	I <sub>B</sub> = 0 mA	35.0			V
BV <sub>EBO</sub>	I <sub>E</sub> = 10.0 mA	I <sub>C</sub> = 0 mA	4			V
I <sub>CBO</sub>	V <sub>CB</sub> = 30.0 V	I <sub>E</sub> = 0			2.0	mA
h <sub>FE</sub>	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 200 mA	35.0			

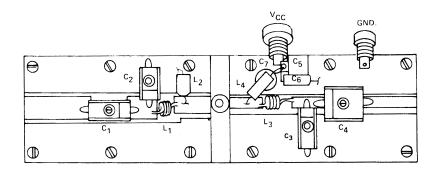
#### **DYNAMIC**

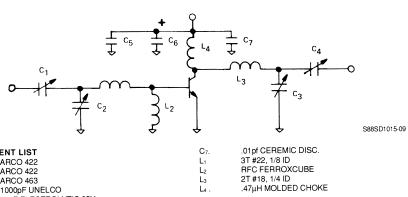
Symbol	Test Conditions			Value			
		Test Conditions		Min.	Тур.	Max.	Units
P <sub>out</sub>	f = 150 MHz	$V_{CC} = 13.5 \text{ V}$		12.5			W
G <sub>P</sub>	f = 150 MHz	V <sub>CC</sub> = 13.5 V		7			dB
P <sub>OUT</sub>	f = 150 MHz	V <sub>CC</sub> = 28 V		30			W
G <sub>P</sub>	f = 150 MHz	V <sub>CC</sub> = 28 V		10			dB
Сов	f = 1 MHz	V <sub>CB</sub> = 30 V	I <sub>E</sub> = 0			250	pF
C <sub>lb</sub>	f = 1 MHz	V <sub>EB</sub> = 0.5 V	I <sub>C</sub> = 0		300		pF



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### **TEST CIRCUIT**



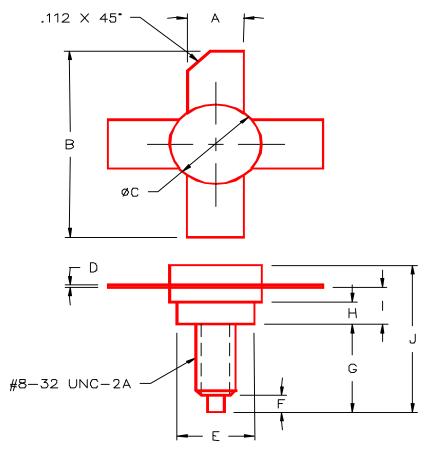






#### PACKAGE MECHANICAL DATA

### PACKAGE STYLE M135



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
Α	.220/5,59	.230/5,84	1	.155/3,94	.175/4,45
В	.980/24,89		J		.750/19,05
С	.370/9,40	.385/9,78			
D	.004/0,10	.007/0,18			
Ε	.320/8,13	.330/8,38			
F	.100/2,54	.130/3,30			
G	.450/11,43	.490/12,45			
Н	.090/2,29	.100/2,54			